

RJH60D2DPP-M0

600V - 12A - IGBT Application: Inverter

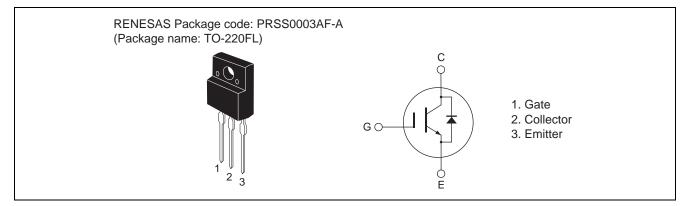
R07DS0160EJ0400 Rev.4.00 Apr 19, 2012

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.7$ V typ. (at $I_C = 12$ A, $V_{GE} = 15$ V, $Ta = 25^{\circ}C$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 80$ ns typ. (at $V_{CC} = 300$ V, $V_{GE} = 15$ V, $I_C = 12$ A, Rg = 5 Ω , $Ta = 25^{\circ}C$, inductive load)

Outline



Absolute Maximum Ratings

				$(Ta = 25^{\circ}C)$	
Item		Symbol	Ratings	Unit	
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V	
Gate to emitter voltage		V _{GES}	±30	V	
Collector current	$Tc = 25^{\circ}C$	Ι _C	25	А	
	Tc = 100°C	Ι _C	12	А	
Collector peak current		ic(peak) ^{Note1}	50	А	
Collector to emitter diode forward current		İ _{DF}	12	А	
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	50	А	
Collector dissipation		Pc ^{Note2}	34	W	
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	3.7	°C/W	
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	4.9	°C/W	
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to +150	°C	

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tc = $25^{\circ}C$



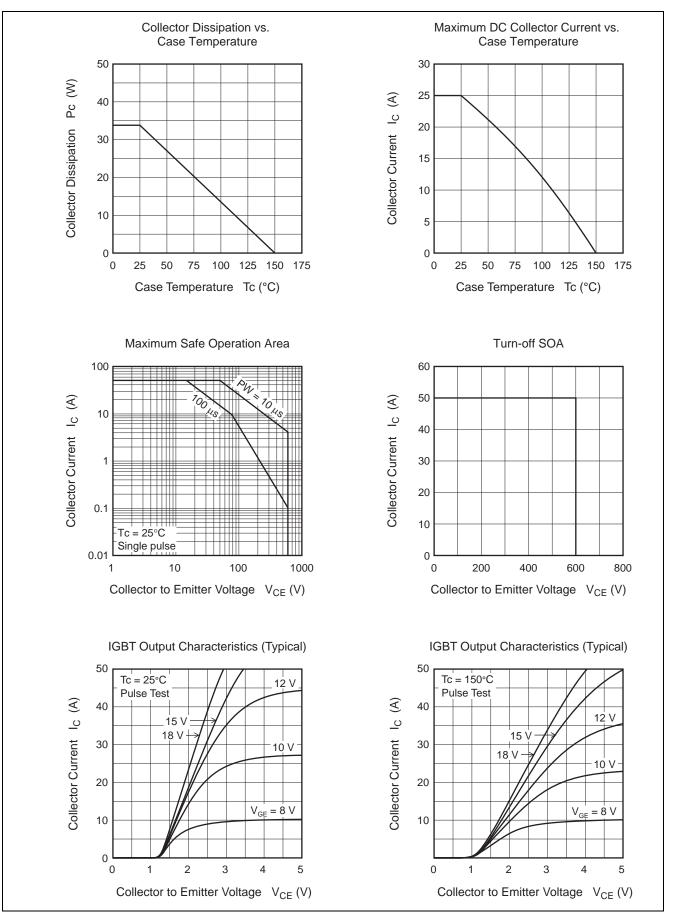
Electrical Characteristics

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage	$V_{BR(CES)}$	600	_	_	V	$I_{C} = 10 \ \mu A, \ V_{GE} = 0$	
Zero gate voltage collector current / Diode reverse current	I_{CES}/I_{R}	_	—	5	μA	$V_{CE} = 600 \text{ V}, \text{ V}_{GE} = 0$	
Gate to emitter leak current	I _{GES}		_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$	
Gate to emitter cutoff voltage	V _{GE(off)}	4.0	_	6.0	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.7	2.2	V	$I_{C} = 12 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.2	_	V	$I_{C} = 25 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies		430	—	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	40		pF	V _{GE} = 0 f = 1 MHz	
Reveres transfer capacitance	Cres		12		pF		
Total gate charge	Qg	_	19	—	nC	V _{GE} = 15 V	
Gate to emitter charge	Qge	_	4	—	nC	V _{CE} = 300 V	
Gate to collector charge	Qgc	_	7	—	nC	I _C = 12 A	
Turn-on delay time	t _{d(on)}	_	32	—	ns	V _{CC} = 300 V	
Rise time	tr	_	13	—	ns	V _{GE} = 15 V	
Turn-off delay time	t _{d(off)}	_	85	—	ns	$I_{C} = 12 A$ $Rg = 5 \Omega$	
Fall time	t _f	_	80	—	ns		
Turn-on energy	Eon	_	0.10	—	mJ	 Inductive load 	
Turn-off energy	Eoff	_	0.16	—	mJ		
Total switching energy	E _{total}		0.26	—	mJ		
Short circuit withstand time	t _{sc}	3.0	5.0		μS	$V_{CC}\leq 360$ V, V_{GE} = 15 V	
			-	-			
FRD Forward voltage	VF		1.2	1.6	V	I _F = 12 A ^{Note3}	
FRD reverse recovery time	t _{rr}	—	100	—	ns	I _F = 12 A	
FRD reverse recovery charge	Qrr		0.2	— —	μC	di _F /dt = 100 A/µs	
FRD peak reverse recovery current	I _{rr}	—	5.0		А		

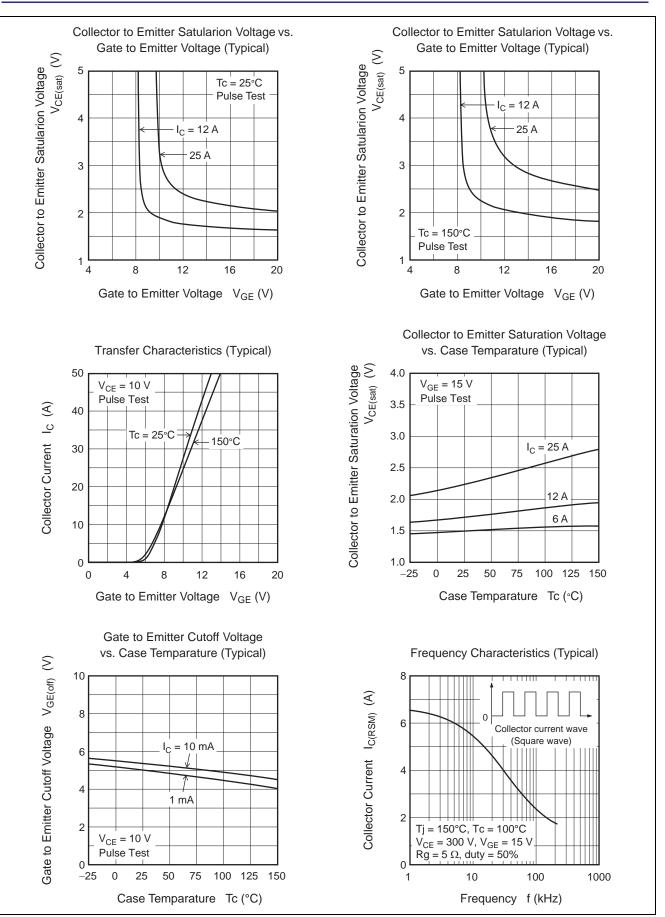
Notes: 3. Pulse test.

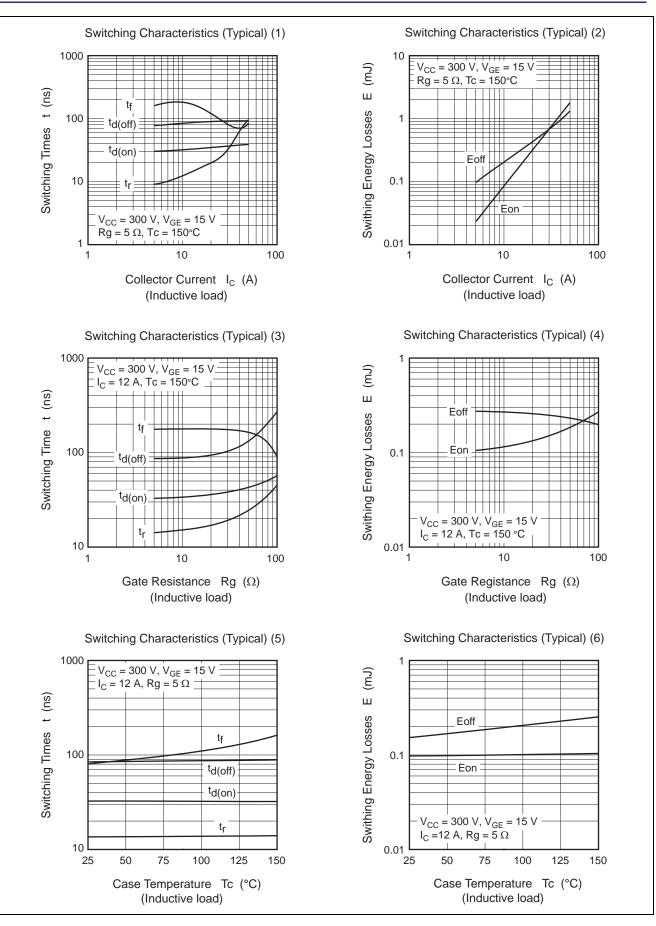


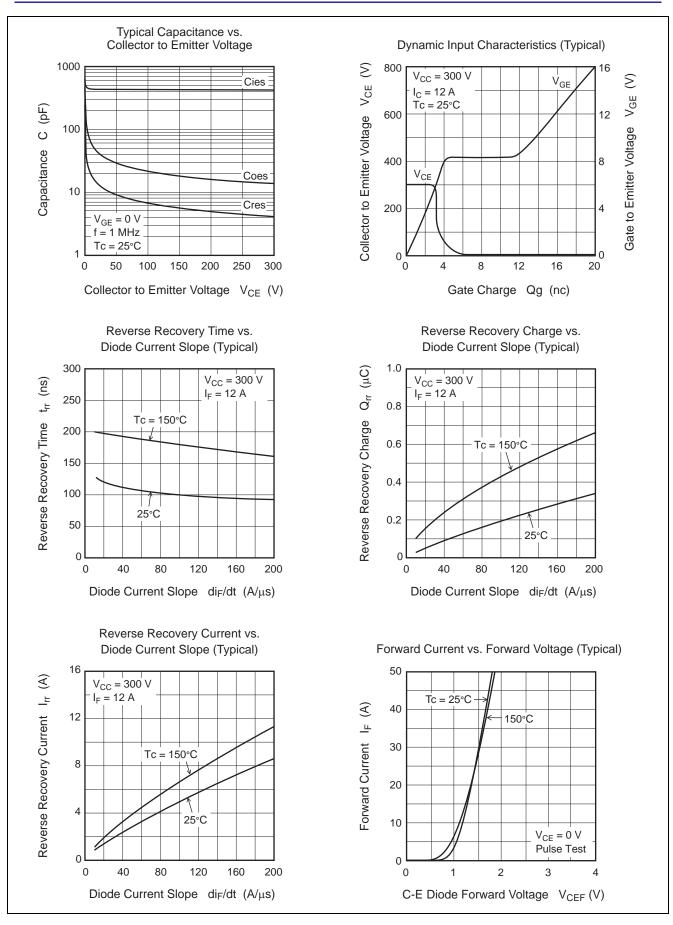
Main Characteristics

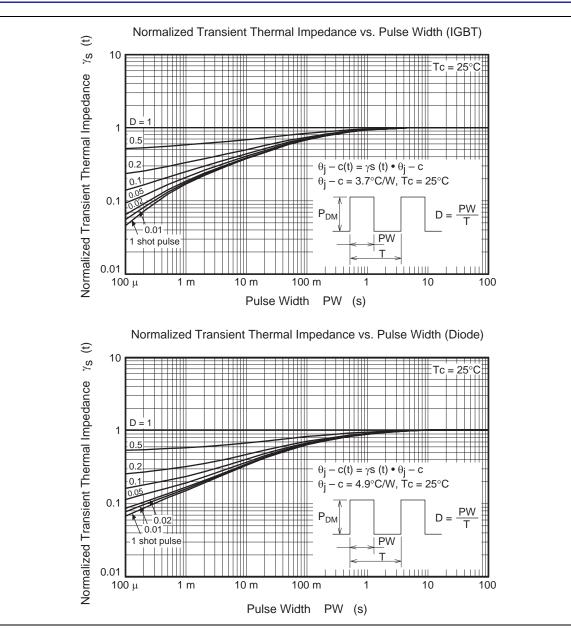




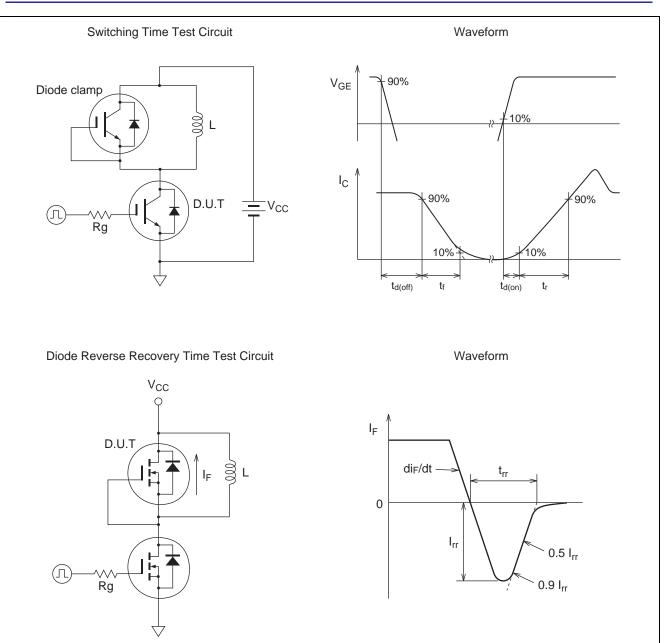






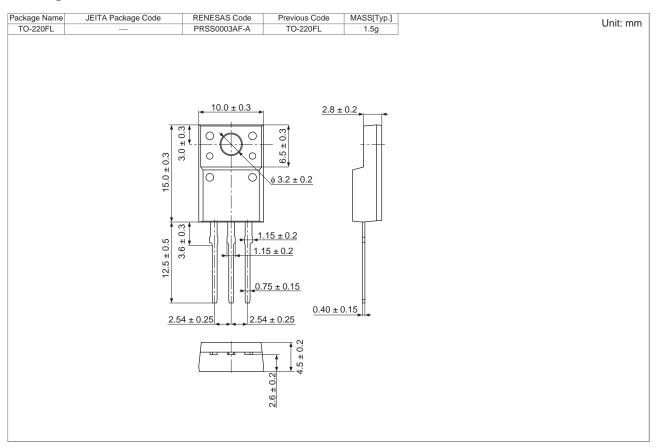








Package Dimension



Ordering Information

Orderable Part No.	Quantity	Shipping Container
RJH60D2DPP-M0#T2	600 pcs	Box (Tube)



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